

Nevskite (BiSe) Structure: AB_hP12_164_c2d_c2d-001

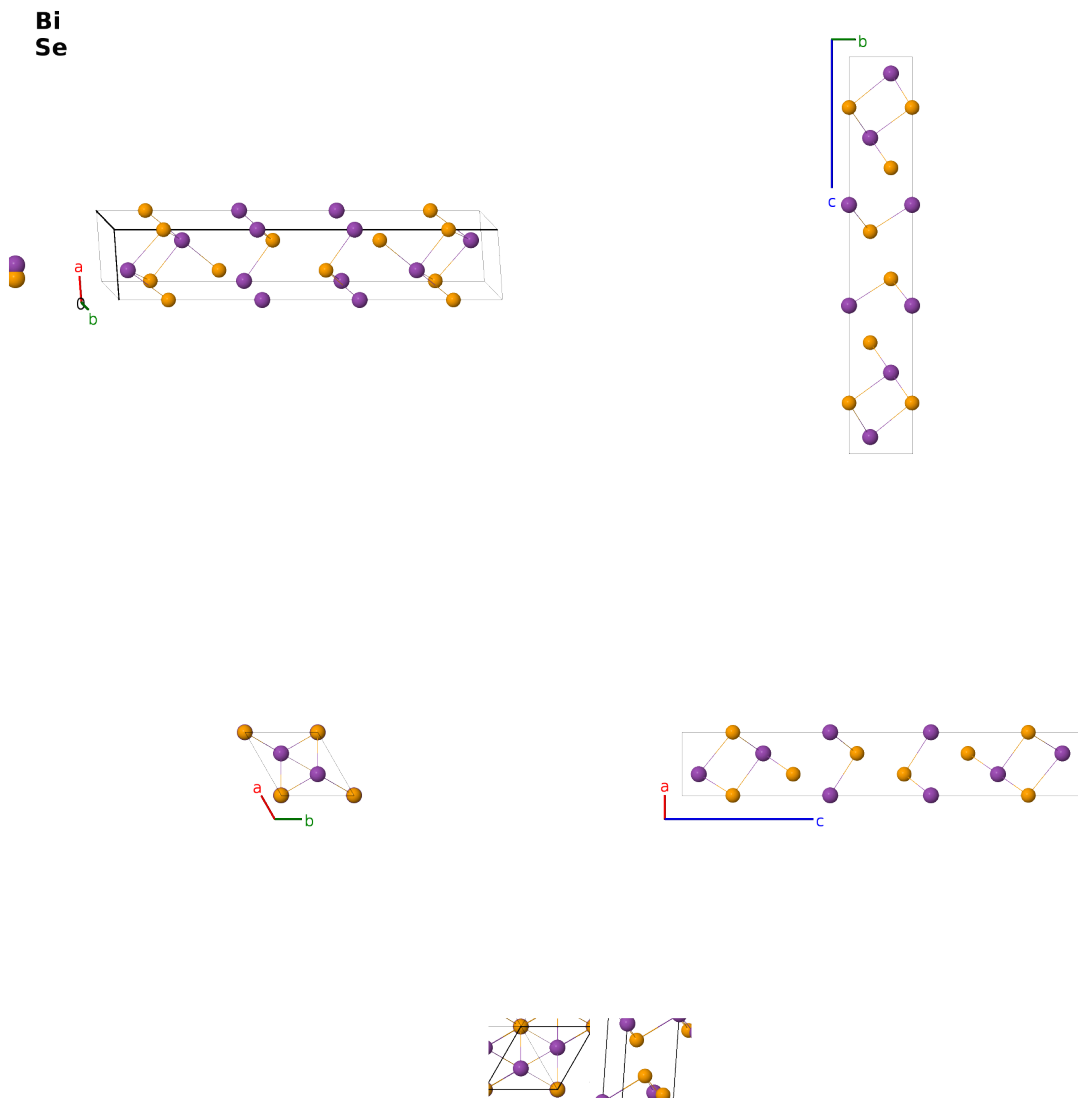
This structure previously used the label(s) **AB_hP12_164_c2d_c2d**. Calls to these addresses will be redirected here.

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<https://aflow.org/prototype-encyclopedia/UEMM>

https://aflow.org/prototype-encyclopedia/AB_hP12_164_c2d_c2d-001



Prototype	BiSe
AFLOW prototype label	AB_hP12_164_c2d_c2d-001
Mineral name	nevskite

ICSD	79019
CCDC	1639282
Pearson symbol	hP12
Space group number	164
Space group symbol	$P\bar{3}m1$
AFLOW prototype command	<code>aflow --proto=AB_hP12_164_c2d_c2d-001</code> <code>--params=$a, c/a, z_1, z_2, z_3, z_4, z_5, z_6$</code>

Other compounds with this structure

BiTe (tsumoite), Bi(S_{0.56}Te_{0.44}) (ingodite)

- The site Bi I actually has the composition (Bi_{0.74}Se_{0.26}), while the site Se II is actual (Se_{0.72},Bi_{0.28}).

Trigonal (Hexagonal) primitive vectors

$$\begin{aligned}
\mathbf{a}_1 &= \frac{1}{2}a \hat{\mathbf{x}} - \frac{\sqrt{3}}{2}a \hat{\mathbf{y}} \\
\mathbf{a}_2 &= \frac{1}{2}a \hat{\mathbf{x}} + \frac{\sqrt{3}}{2}a \hat{\mathbf{y}} \\
\mathbf{a}_3 &= c \hat{\mathbf{z}}
\end{aligned}$$



Basis vectors

	Lattice coordinates		Cartesian coordinates	Wyckoff position	Atom type
$\mathbf{B}_1$	$= z_1 \mathbf{a}_3$	$=$	$c z_1 \hat{\mathbf{z}}$	(2c)	Bi I
$\mathbf{B}_2$	$= -z_1 \mathbf{a}_3$	$=$	$-c z_1 \hat{\mathbf{z}}$	(2c)	Bi I
$\mathbf{B}_3$	$= z_2 \mathbf{a}_3$	$=$	$c z_2 \hat{\mathbf{z}}$	(2c)	Se I
$\mathbf{B}_4$	$= -z_2 \mathbf{a}_3$	$=$	$-c z_2 \hat{\mathbf{z}}$	(2c)	Se I
$\mathbf{B}_5$	$= \frac{1}{3} \mathbf{a}_1 + \frac{2}{3} \mathbf{a}_2 + z_3 \mathbf{a}_3$	$=$	$\frac{1}{2}a \hat{\mathbf{x}} + \frac{\sqrt{3}}{6}a \hat{\mathbf{y}} + c z_3 \hat{\mathbf{z}}$	(2d)	Bi II
$\mathbf{B}_6$	$= \frac{2}{3} \mathbf{a}_1 + \frac{1}{3} \mathbf{a}_2 - z_3 \mathbf{a}_3$	$=$	$\frac{1}{2}a \hat{\mathbf{x}} - \frac{\sqrt{3}}{6}a \hat{\mathbf{y}} - c z_3 \hat{\mathbf{z}}$	(2d)	Bi II
$\mathbf{B}_7$	$= \frac{1}{3} \mathbf{a}_1 + \frac{2}{3} \mathbf{a}_2 + z_4 \mathbf{a}_3$	$=$	$\frac{1}{2}a \hat{\mathbf{x}} + \frac{\sqrt{3}}{6}a \hat{\mathbf{y}} + c z_4 \hat{\mathbf{z}}$	(2d)	Bi III
$\mathbf{B}_8$	$= \frac{2}{3} \mathbf{a}_1 + \frac{1}{3} \mathbf{a}_2 - z_4 \mathbf{a}_3$	$=$	$\frac{1}{2}a \hat{\mathbf{x}} - \frac{\sqrt{3}}{6}a \hat{\mathbf{y}} - c z_4 \hat{\mathbf{z}}$	(2d)	Bi III
$\mathbf{B}_9$	$= \frac{1}{3} \mathbf{a}_1 + \frac{2}{3} \mathbf{a}_2 + z_5 \mathbf{a}_3$	$=$	$\frac{1}{2}a \hat{\mathbf{x}} + \frac{\sqrt{3}}{6}a \hat{\mathbf{y}} + c z_5 \hat{\mathbf{z}}$	(2d)	Se II
$\mathbf{B}_{10}$	$= \frac{2}{3} \mathbf{a}_1 + \frac{1}{3} \mathbf{a}_2 - z_5 \mathbf{a}_3$	$=$	$\frac{1}{2}a \hat{\mathbf{x}} - \frac{\sqrt{3}}{6}a \hat{\mathbf{y}} - c z_5 \hat{\mathbf{z}}$	(2d)	Se II
$\mathbf{B}_{11}$	$= \frac{1}{3} \mathbf{a}_1 + \frac{2}{3} \mathbf{a}_2 + z_6 \mathbf{a}_3$	$=$	$\frac{1}{2}a \hat{\mathbf{x}} + \frac{\sqrt{3}}{6}a \hat{\mathbf{y}} + c z_6 \hat{\mathbf{z}}$	(2d)	Se III
$\mathbf{B}_{12}$	$= \frac{2}{3} \mathbf{a}_1 + \frac{1}{3} \mathbf{a}_2 - z_6 \mathbf{a}_3$	$=$	$\frac{1}{2}a \hat{\mathbf{x}} - \frac{\sqrt{3}}{6}a \hat{\mathbf{y}} - c z_6 \hat{\mathbf{z}}$	(2d)	Se III

References

- [1] E. Gaudin, S. Jobic, M. Evain, R. Brec, and J. Rouxel, *Charge balance in some Bi_xSe_y phases through atomic structure determination and band structure calculations*, Mater. Res. Bull. **30**, 549–561 (1995), doi:10.1016/0025-5408(95)00030-5.

Found in

- [1] K. Majhi, K. Pal, H. Lohani, A. Banerjee, P. Mishra, A. K. Y. R. Ganesan, B. R. Sekhar, U. V. Waghmare, and P. S. A. Kumar, *Emergence of a weak topological insulator from the Bi_xSe_y family*, Appl. Phys. Lett. **110**, 162102 (2017), doi:10.1063/1.4981875.

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